

May 1991

HARRIS SEMICONDUCTOR
Features

- Ultrafast with Soft Recovery Characteristic ($t_{rr} < 75\text{ns}$)
- +175°C Rated Junction Temperature
- Reverse Voltage Up to 1000V
- Avalanche Energy Rated

Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

Description

MUR870E, MUR880E, MUR890E, MUR8100E and RUR870, RUR880, RUR890, RUR8100 are ultrafast dual diodes ($t_{rr} < 75\text{ns}$) with soft recovery characteristics ($t_a/t_b \approx 0.5$). They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction.

These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits thus reducing power loss in the switching transistor.

All are supplied in TO-220AC packages.

Package

TO-220AC
TOP VIEW

Symbol

Absolute Maximum Ratings ($T_C = +25^\circ\text{C}$)

	MUR870E RUR870	MUR880E RUR880	MUR890E RUR890	MUR8100E RUR8100
Peak Repetitive Reverse Voltage..... V_{RRM}	700V	800V	900V	1000V
Working Peak Reverse Voltage..... V_{RWM}	700V	800V	900V	1000V
DC Blocking Voltage..... V_R	700V	800V	900V	1000V
Average Rectified Forward Current..... $I_{F(AV)}$ (Total device forward current at rated V_R and $T_C = 150^\circ\text{C}$)	8A	8A	8A	8A
Peak Forward Repetitive Current..... I_{FRM} (Rated V_R , square wave 20kHz)	16A	16A	16A	16A
Nonrepetitive Peak Surge Current..... I_{FSM} (Surge applied at rated load condition halfwave 1 phase 60Hz)	100A	100A	100A	100A
Operating and Storage Temperature..... T_{STG}, T_J	-55°C to +175°C	-55°C to +175°C	-55°C to +175°C	-55°C to +175°C

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SYMBOL	TEST CONDITION	LIMITS												UNITS
		MUR870E, RUR870			MUR880E, RUR880			MUR890E, RUR890			MUR8100E, RUR8100			
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V _F	I _F = 8A T _C = +150°C			1.50			1.50			1.50			1.50	V
	I _F = 8A T _C = +25°C			1.80			1.80			1.80			1.8	V
I _R @ T _C = +150°C	V _R = 700V			500										μA
	V _R = 800V						500							μA
	V _R = 900V									500				μA
	V _R = 1000V												500	μA
I _R @ T _C = +25°C	V _R = 700V			25										μA
	V _R = 500V						25							μA
	V _R = 600V									25				μA
	V _R = 1000V												25	μA
t _{rr}	I _F = 1A			100			100			100			100	ns
	I _F = 8A			110			110			110			110	ns
t _a	I _F = 1A		40			40			40			40		ns
	I _F = 8A		45			45			45			45		ns
t _b	I _F = 1A		20			20			20			20		ns
	I _F = 8A		20			20			20			20		ns
R _{θjc}				2.0			2.0			2.0			2.0	°C/W
W _{avl}	see Fig. 7&8			20			20			20			20	mJ

Definitions

V_F = Instantaneous forward voltage ($p_w = 300\mu\text{s}$, $D = 2\%$).

I_R = Instantaneous reverse current ($p_w = 300\mu\text{s}$, $D = 2\%$).

t_{rr} = Reverse recovery time at $dI_F/dt = 100\text{A}/\mu\text{s}$ (See Figure 2), summation of $t_a + t_b$.

t_a = Time to reach peak reverse current at $dI_F/dt = 100\text{A}/\mu\text{s}$ (See Figure 2).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} . (See Figure 2)

$R_{\theta jc}$ = Thermal resistance junction to case.

W_{avl} = Controlled avalanche energy (See Figures 7 & 8).

p_w = pulse width.

D = duty cycle.

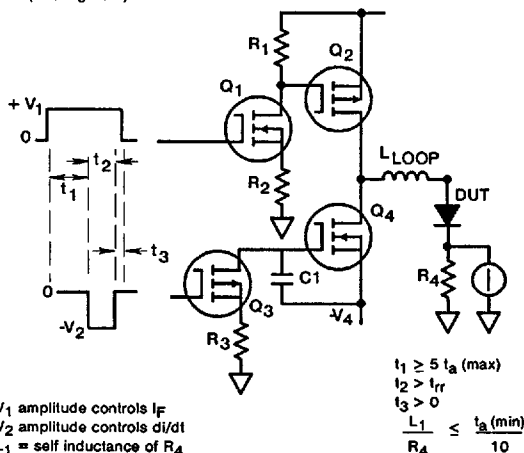


FIGURE 1. t_{rr} TEST CIRCUIT

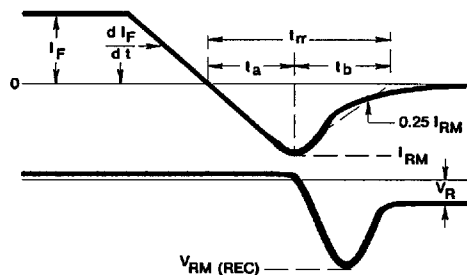


FIGURE 2. DEFINITIONS OF t_{rr} , t_a AND t_b

ULTRA-FAST RECTIFIERS

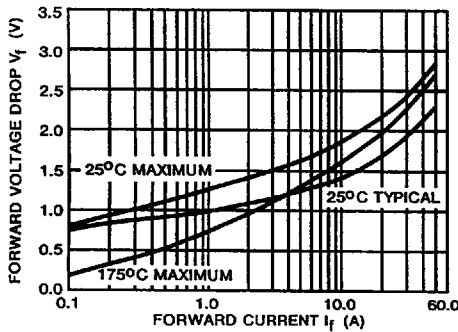


FIGURE 3. FORWARD VOLTAGE vs FORWARD CURRENT CHARACTERISTIC

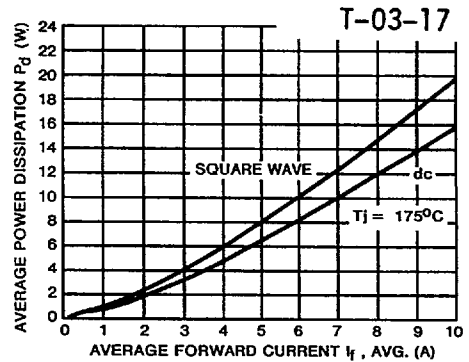


FIGURE 4. AVERAGE FORWARD CURRENT vs AVERAGE POWER DISSIPATION

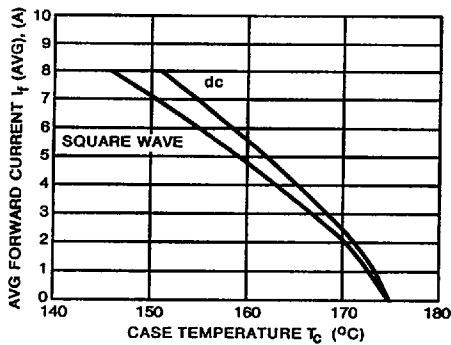


FIGURE 5. AVERAGE FORWARD CURRENT vs CASE TEMPERATURE

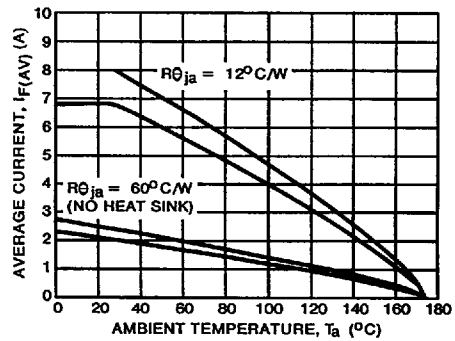


FIGURE 6. AVERAGE FORWARD CURRENT vs AMBIENT TEMPERATURE

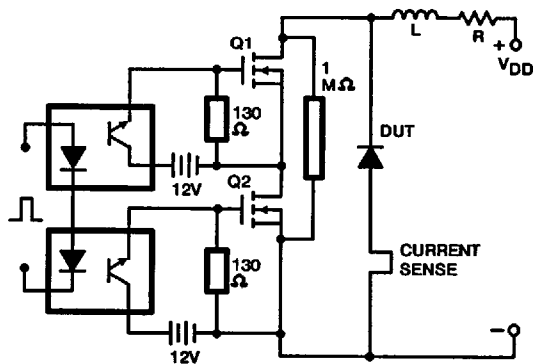


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

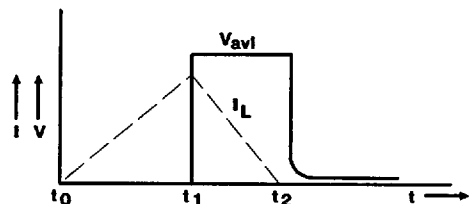


FIGURE 8. CURRENT VOLTAGE WAVEFORM

$$I_{L\text{peak}} = 1\text{A}, L = 40\text{mH}, R < 0.1\Omega, W_{\text{avi}} = (1/2) L I_L^2 [V_{\text{avi}} / (V_{\text{avi}} - V_{\text{dd}})]$$